

# RJH1CV6DPK

1200V - 30A - IGBT Application: Inverter R07DS0747EJ0200 Rev.2.00 Jun 12, 2012

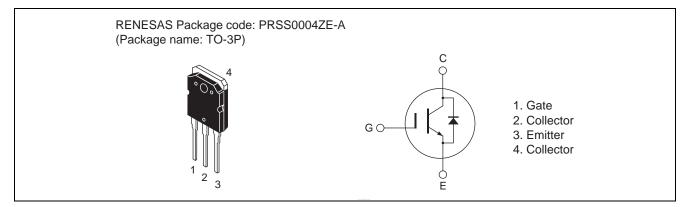
Datasheet

## Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage  $V_{CE(sat)} = 1.8 \text{ V typ.}$  (at  $I_C = 30 \text{ A}$ ,  $V_{GE} = 15 \text{ V}$ ,  $Ta = 25^{\circ}\text{C}$ )
- Built-in fast recovery diode ( $t_{rr} = 180$  ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching

 $t_f = 120$  ns typ. (at  $V_{CC} = 600$  V,  $V_{GE} = 15$  V,  $I_C = 30$  A, Rg = 5  $\Omega$ ,  $Ta = 25^{\circ}C$ , inductive load)

## Outline



## **Absolute Maximum Ratings**

				$(Ta = 25^{\circ}C)$
Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V <sub>CES</sub> / V <sub>R</sub>	1200	V
Gate to emitter voltage		V <sub>GES</sub>	±30	V
Collector current	$Tc = 25^{\circ}C$	Ιc	60	А
	Tc = 100°C	Ιc	30	А
Collector peak current		ic(peak) <sup>Note1</sup>	90	А
Collector to emitter diode forward current		I <sub>DF</sub>	30	А
Collector to emitter diode forward peak current		i <sub>DF</sub> (peak) <sup>Note1</sup>	90	А
Collector dissipation		Pc <sup>Note2</sup>	290	W
Junction to case thermal resistance (IGBT)		θj-c <sup>Note2</sup>	0.43	°C/W
Junction to case thermal resistance (Diode)		θj-cd <sup>Note2</sup>	0.69	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1.  $PW \le 10 \ \mu s$ , duty cycle  $\le 1\%$ 

2. Value at Tc = 25°C



# **Electrical Characteristics**

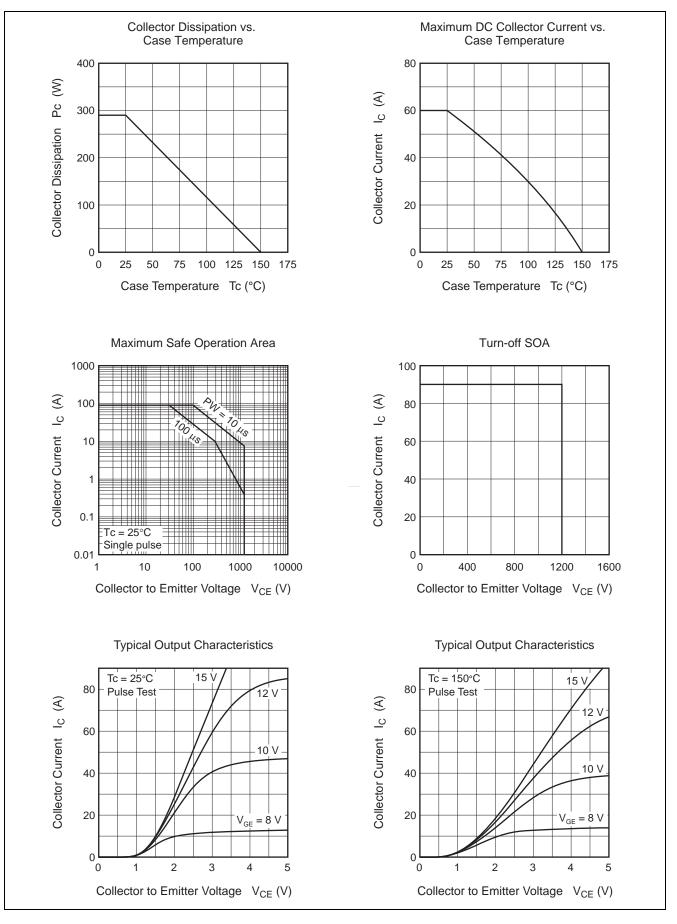
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Collector to emitter breakdown voltage	V <sub>(BR)CES</sub>	1200	—	—	V	$I_{C} = 10 \ \mu A, \ V_{GE} = 0$
Zero gate voltage collector current / Diode reverse current	I <sub>CES</sub> /I <sub>R</sub>	_	—	5	μA	$V_{CE} = 1200 \text{ V}, \text{ V}_{GE} = 0$
Gate to emitter leak current	I <sub>GES</sub>	_	—	±1	μA	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$
Gate to emitter cutoff voltage	V <sub>GE(off)</sub>	4.5	—	6.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>		1.8	2.6	V	$I_{C} = 30 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
	V <sub>CE(sat)</sub>	_	2.6	_	V	$I_{C} = 60 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
Input capacitance	Cies		1600	—	pF	$V_{CE} = 25 V$ $V_{GE} = 0$ $f = 1 MHz$
Output capacitance	Coes	_	85	_	pF	
Reverse transfer capacitance	Cres	_	43	—	pF	
Total gate charge	Qg	_	105	—	nC	V <sub>GE</sub> = 15 V V <sub>CE</sub> = 300 V I <sub>C</sub> = 35 A
Gate to emitter charge	Qge	_	14	—	nC	
Gate to collector charge	Qgc	_	55	—	nC	
Turn-on delay time	t <sub>d(on)</sub>	_	46	—	ns	$V_{CC} = 600 V$ $V_{GE} = 15 V$ $I_C = 30 A$ $Rg = 5 \Omega$ Inductive load
Rise time	tr	_	33	—	ns	
Turn-off delay time	t <sub>d(off)</sub>	_	125	—	ns	
Fall time	t <sub>f</sub>	_	120	—	ns	
Turn-on energy	Eon		2.3	_	mJ	
Turn-off energy	E <sub>off</sub>	_	1.7	—	mJ	
Total switching energy	E <sub>total</sub>		4.0	—	mJ	
Short circuit withstand time	t <sub>sc</sub>	_	5	—	μs	$\label{eq:V_CC} \begin{array}{l} V_{CC} \leq 720 \ \text{V}, \ V_{GE} = 15 \ \text{V} \\ Tc \leq 125^{\circ}\text{C} \end{array}$
ERD forward voltage	Ve		2.0	I	V	$I_{r} = 30 \text{ A}^{\text{Note3}}$

FRD forward voltage	V <sub>F</sub>		2.0	—	V	$I_F = 30 A^{Note3}$
FRD reverse recovery time	t <sub>rr</sub>	_	180	—	ns	I <sub>F</sub> = 30 A
FRD reverse recovery charge	Qrr	_	0.63	—	μC	di <sub>F</sub> /dt = 100 A/µs
FRD peak reverse recovery current	l <sub>rr</sub>	_	9.2	—	А	

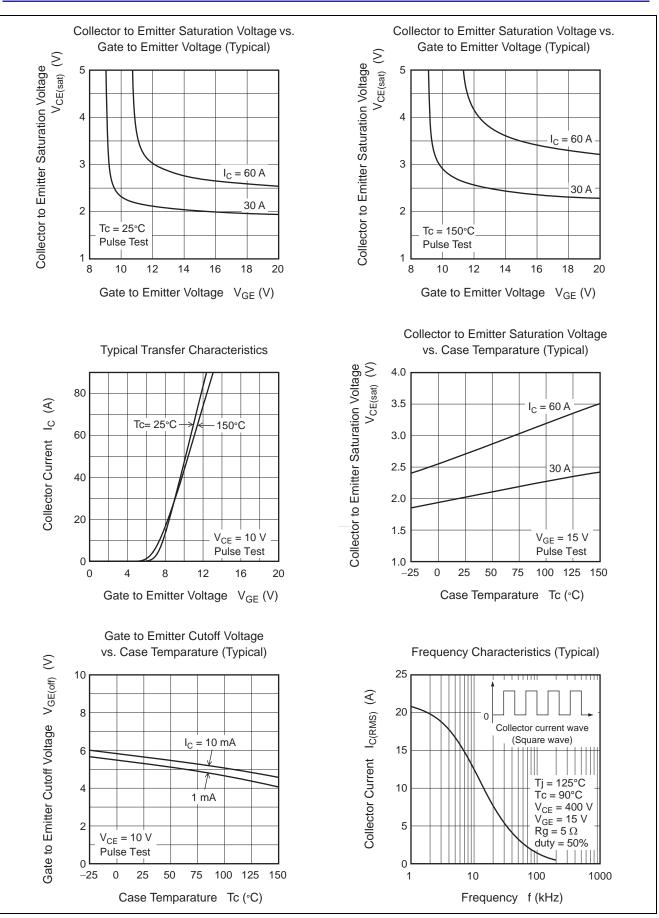
Notes: 3. Pulse test.

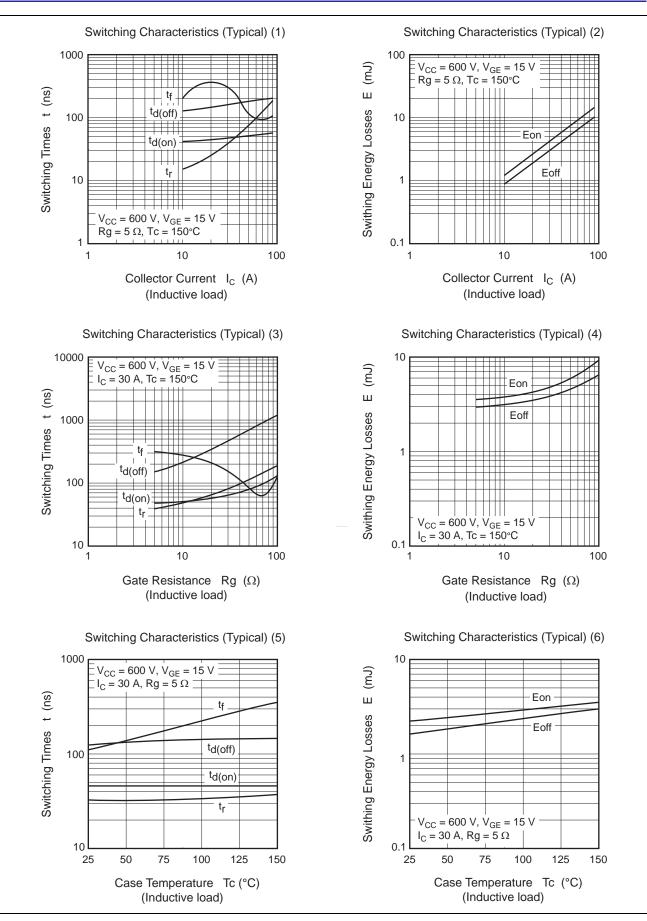


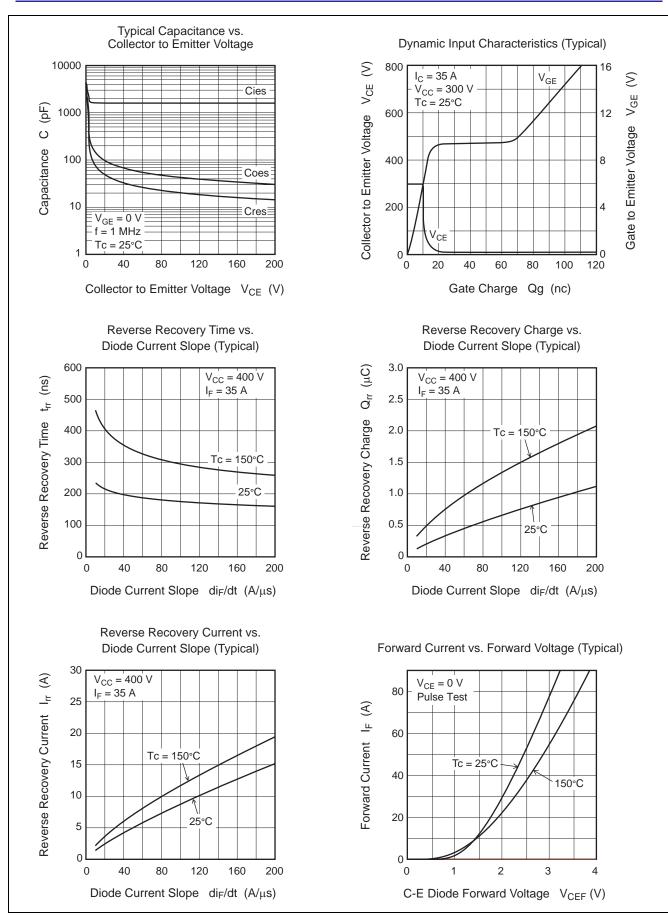
### **Main Characteristics**



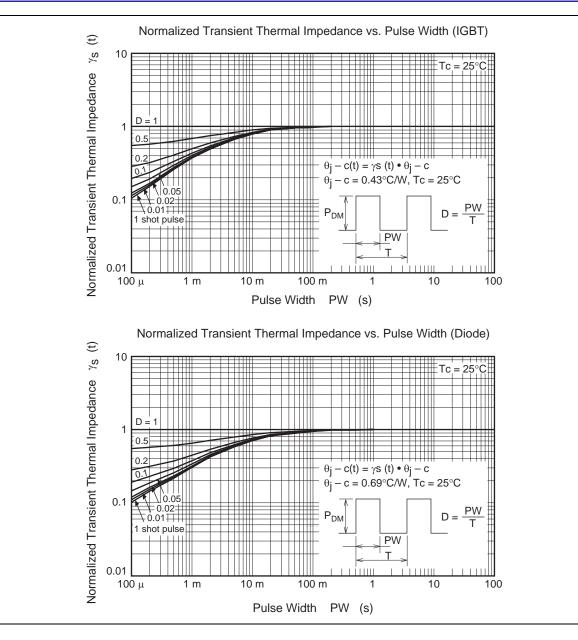




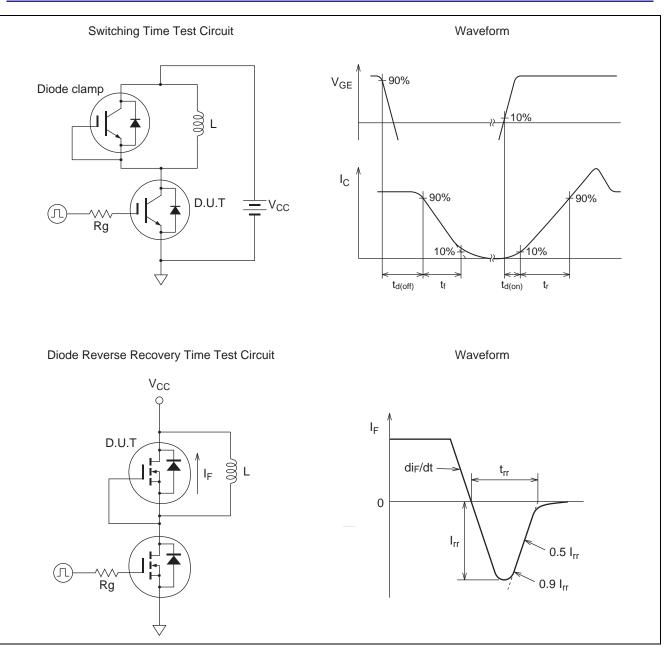














# Package Dimension

Package Name TO-3P	JEITA Package Code SC-65	RENESAS Code	Previous Code TO-3P / TO-3PV	MASS[Typ.]	
10-3P	SC-65	PRSS0004ZE-A 15.6 ± 0.3	1.0 ± 0.2 1.0 ± 0.2 1.0 ± 0.2 1.0 ± 0.2 1.0 ± 0.2 1.0 ± 0.2 1.0 ± 0.2	5.0g 4.8 ± 0.2 1.5 0.6 ± 0.2	Unit: mm
	<u>5.45 ± 0</u>		<u>2</u> .0 <u>1</u> <u>5.45 ± 0.5</u>		

# **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJH1CV6DPK-00#T0	360 pcs	Box (Tube)



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